MC100EPT21

Differential LVPECL to LVTTL Translator

The MC100EPT21 is a Differential LVPECL to LVTTL translator. Because LVPECL (Positive ECL) levels are used only +3.3V and ground are required. The small outline 8–lead SOIC package makes the EPT21 ideal for applications which require the translation of a clock or data signal.

The VBB output allows the EPT21 to also be used in a <u>single</u>-ended input mode. In this mode the VBB output is tied to the $\overline{D0}$ input for a non-inverting buffer or the D0 input for an inverting buffer. If used, the VBB pin should be bypassed to ground via a $0.01\mu F$ capacitator.

- 1.4ns Typical Propagation Delay
- 275MHz Fmax (Clock bit stream, not pseudo-random)
- Differential LVPECL inputs
- Small Outline SOIC Package
- 24mA TTL outputs
- Flow Through Pinouts
- Internal Input Resistors: Pulldown on D, Pulldown and Pullup on \overline{D}
- Q Output will default LOW with inputs open or at GND
- ESD Protection: >1500V HBM, >100V MM
- VBB Output
- New Differential Input Common Mode Range
- Moisture Sensitivity Level 1, Indefinite Time Out of Drypack.
 For Additional Information, See Application Note AND8003/D
- Flammability Rating: UL-94 code V-0 @ 1/8", Oxygen Index 28 to 34
- Transistor Count = 81 devices

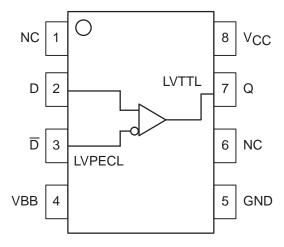


Figure 1. 8-Lead Pinout (Top View) and Logic Diagram



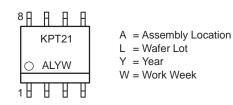
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MARKING DIAGRAM



*For additional information, see Application Note AND8002/D

PIN DESCRIPTION					
PIN	FUNCTION				
Q	LVTTL Output				
D, \overline{D}	Differential LVPECL Input Pair				
Vcc	Positive Supply				
V _{BB}	Output Reference Voltage				
GND	GND Ground				

ORDERING INFORMATION

Device	Package	Shipping			
MC100EPT21D	SOIC	98 Units/Rail			
MC100EPT21DR2	SOIC	2500 Tape & Reel			

MC100EPT21

MAXIMUM RATINGS*

Symbol	Parameter	Value	Unit		
VCC	Power Supply (GND = 0V)		0 to 3.8	VDC	
VI	Input Voltage (GND = 0V, V _I not more positive that	ın VCC)	0 to 3.8	VDC	
l _{out}	Output Current	Continuous Surge	50 100	mA	
I _{BB}	V _{BB} Sink/Source Current†	VBB Sink/Source Current†			
TA	Operating Temperature Range	-40 to +85	°C		
T _{stg}	Storage Temperature		-65 to +150	°C	
θЈΑ	Thermal Resistance (Junction–to–Ambient)	Still Air 500lfpm	190 130	°C/W	
θЈС	Thermal Resistance (Junction-to-Case)		41 to 44 ± 5%	°C/W	
T _{sol}	Solder Temperature (<2 to 3 Seconds: 245°C des	265	°C		

^{*} Maximum Ratings are those values beyond which damage to the device may occur.

DC CHARACTERISTICS (V_{CC} = 3.3V \pm 0.3V; GND = 0V; T_A = -40°C to 85°C)

Symbol	Characteristic	Min	Тур	Max	Unit	
ICCH	Power Supply Current (Outputs set to HIGH)	5.0	12	20	mA	
ICCL	Power Supply Current (Outputs set to LOW)		8.0	18	26	mA
V _{IH}	Input HIGH Voltage (V _{CC} = 3.3) (Note 1.)		2135		2420	mV
V _{IL}	Input LOW Voltage (V _{CC} = 3.3) (Note 1.)		1490		1825	mV
lн	Input HIGH Current				150	μΑ
IIL	Input LOW Current $\frac{D}{\overline{D}}$		-150		0.5	μА
Vон	Output HIGH Voltage ($I_{OH} = -3.0$ mA) (Note 2.)		2.4			V
VOL	Output LOW Voltage (I _{OL} = 24mA) (Note 2.)				0.5	V
los	Output Short Circuit Current		-130		-80	mA
VIHCMR	Input HIGH Voltage Common Mode Range (Note 3.)		2.0		3.3	V
V_{BB}	Output Voltage Reference			2.0		V

NOTE: 100EP circuits are designed to meet the DC specifications shown in the above table after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse airflow greater than 500lfpm is maintained.

AC CHARACTERISTICS ($V_{CC} = 3.3V \pm 0.3V$; GND = 0V)

			-40°C		25°C			85°C				
Symbol	Characteristic		Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
f _{max}	Maximum Toggle Frequency (Note 4.)		275	350		275	350		275	350		MHz
tPLH, tPHL	Propagation Delay to Output Differential		1000 1000	1450 1400	1800 1800	1000 1000	1450 1400	1800 1800	1000 1000	1450 1400	1900 1900	ps
tSK++ tSK tSKPP	Output-to-Output Skew++ Output-to-Output Skew Part-to-Part Skew (Note 5.)			60 25 500			60 25 500			60 25 500		ps
^t JITTER	Cycle-to-Cycle Jitter			TBD			TBD			TBD		ps
VPP	Input Voltage Swing (Diff.)		150	800	1200	150	800	1200	150	800	1200	mV
t _r	Output Rise/Fall Times (0.8V – 2.0V)	Q, Q	330	500	900	330	500	900	330	500	900	ps

F_{max} guaranteed for functionality only. V_{OL} and V_{OH} levels are guaranteed at DC only.
 Skews are measured between outputs under identical transitions.

[†] Use for inputs of same package only.

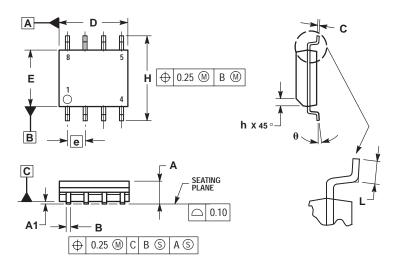
^{1.} All values vary 1:1 with V_{CC}.

All loading with 500 ohms to GND, CL = 20pF.
 V_{IHCMR} min varies 1:1 with GND, max varies 1:1 with V_{CC}.

MC100EPT21

PACKAGE DIMENSIONS

SO-8 **D SUFFIX** PLASTIC SOIC PACKAGE CASE 751-06 ISSUE T



- NOTES:

 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.

 2. DIMENSIONS ARE IN MILLIMETER.

 3. DIMENSION D AND E DO NOT INCLUDE MOLD PROTRUSION.

 4. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.

 5. DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 TOTAL IN EXCESS OF THE B DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIMETERS							
DIM	MIN	MAX						
Α	1.35	1.75						
A1	0.10	0.25						
В	0.35	0.49						
С	0.19	0.25						
D	4.80	5.00						
Ε	3.80	4.00						
е	1.27	BSC						
Н	5.80	6.20						
h	0.25	0.50						
L	0.40	1.25						
θ	0 °	7 °						

MC100FPT21

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